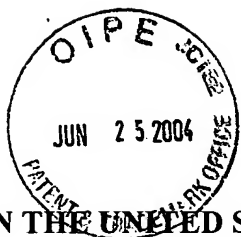


MICRON.225C1

PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant	:	Zhu et al.
Appl. No.	:	10/804,584
Filed	:	March 16, 2004
For	:	MAGNETO-RESISTIVE MEMORY CELL STRUCTURES WITH IMPROVED SELECTIVITY
Examiner	:	Unknown

PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Prior to examination on the merits, please amend the subject application as indicated below.

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 7 of this paper.